NSN 5961-01-357-5420

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-357-5420 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.208 inches and 0.230 inches **Function For Which Designed: Amplifier Electrode Internally-electrically Connected To Case:** Source **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 35.0 drain to gate voltage all transistor and 20.0 drain to source voltage all transistor **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current of standard range all transistor **Power Rating Per Characteristic:** 360.0 milliwatts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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